

NJM2900/3900

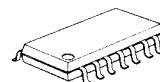
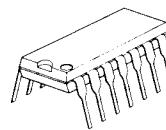
The NJM2900/3900 consist of four independent, dual input, internally compensated amplifiers which were designed specifically to operate off of a single power supply voltage and to provide a large output voltage swing. These amplifiers make use of a current mirror to achieve the non-inverting input function. Application areas include: ac amplifiers, RC active filters, low frequency triangle, squarewave and pulse waveform generation circuits, tachometers and low speed, high voltage digital logic gates.

■ Package Outline

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■ Absolute Maximum Ratings (Ta=25°C)

Supply Voltage	V ⁺ (2900)	+36V ($\pm 18V$)
	V ⁺ (3900)	+32V ($\pm 16V$)
Power Dissipation	P _D (N-Type)	500mW
	(M,E-Type)	300mW
Input Current	I _{IN}	20mA
Operating Temperature Range	T _{opr} (2900)	-40~+85°C
	T _{opr} (3900)	-20~+75°C
Storage Temperature Range	T _{stg}	-40~+125°C



NJM2900N

NJM2900M

NJM3900N

NJM3900M



NJM2900E

NJM3900E

■ Electrical Characteristics (Ta=25°C, V⁺=+15V)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Voltage Gain	A _V	Open Loop, f=100Hz	61.5	69	—	dB
Input Resistance	R _{IN}	Open Loop, Inverting Input	—	1	—	MΩ
Output Resistance	R _O	Open Loop	—	8	—	kΩ
Unity Gain Bandwidth	GB	A _V =1, Inverting Input (note 1)	—	2.5	—	MHz
Input Bias Current	I _B	Inverting Input	—	30	200	nA
Slew Rate	SR	Positive Output Swing	—	0.5	—	V/μs
		Negative Output Swing	—	20	—	V/μs
Supply Current	I _{CC}	R _L =∞	—	6.2	10	mA
Output High Voltage Swing	V _{OH}	I _{IN} ⁻ =0, I _{IN} ⁺ =0, R _L =5.1kΩ	13.5	14.2	—	V
Output Low Voltage Swing	V _{OL}	I _{IN} ⁻ =10μA, I _{IN} ⁺ =0, R _L =5.1kΩ	—	0.09	0.2	V
Output Source Current	I _{SOURCE}	(note 2)	6	18	—	mA
Output Sink Current	I _{SINK}	(note 2)	0.5	1.3	—	mA
Power Supply Rejection	SVR	f=100Hz	—	70	—	dB
Mirror Gain	M	I _{IN} ⁺ =200μA (note 3)	0.90	1	1.1	μA/μA
Mirror Current	I _M	(note 4)	—	10	500	μA
Negative Input Current	I _{IN} ⁻	(note 5)	—	1.0	—	mA

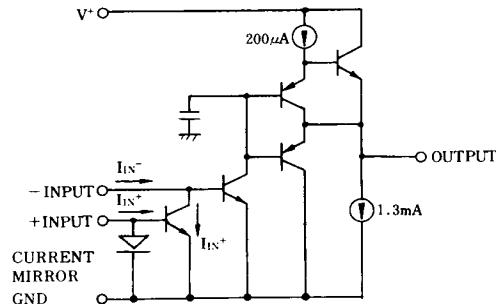
note 1. The output sink current capacity can be increased by over-driving the inverting input.

2. This standard shows the current amplification degree of a current mirror when NJM2900/3900 serves as a non-inverting amplifier.

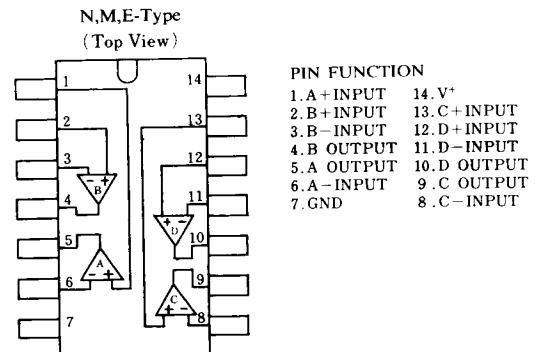
3. The V_{BE} matching of input stage transistors is designed to meet a mirror current of about 10μA.

4. The input clamp transistor is designed in such a way as the input voltage is not lower than about 0.3V. If the negative input current exceeds 4mA, the output may drop to a low voltage.

■ Equivalent Circuit

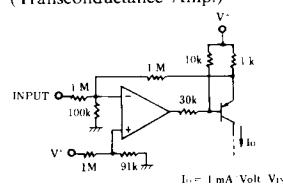


■ Connection Diagram

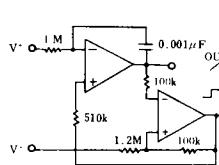


■ Typical Application ($V^+ = 15V$)

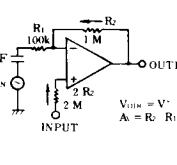
Voltage Control Current Source
(Transconductance Amp.)



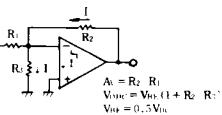
Triangle/Square Wave Generator



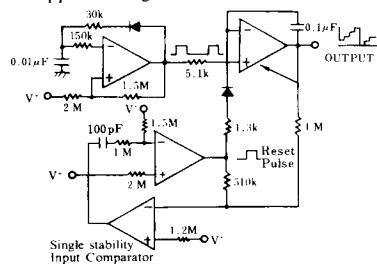
Inverting Amplifier



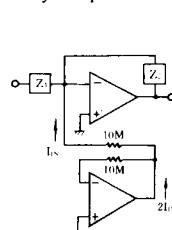
V_{BE} Bias



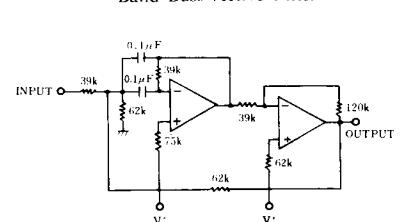
Stepped wave generator/Pulse Counter



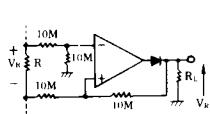
Auxiliary Amp. for In Supplier



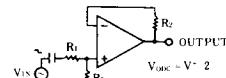
Band Buss Active Filter



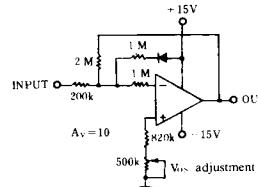
Differential input signal detecting circuit



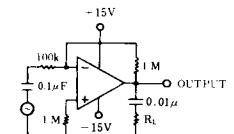
Non-Inverting Amplifier



Double Voltage ($V^+/V^- = \pm 15V$)
Non inverting AC Amp.



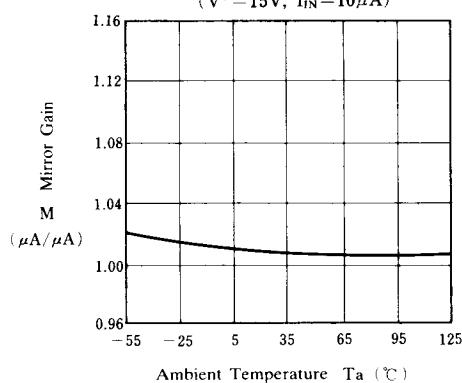
AC Amp.



■ Typical Characteristics

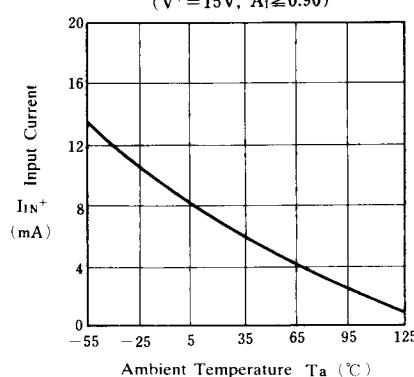
Mirror Gain vs. Temperature

($V^+ = 15V$, $I_{IN} = 10\mu A$)



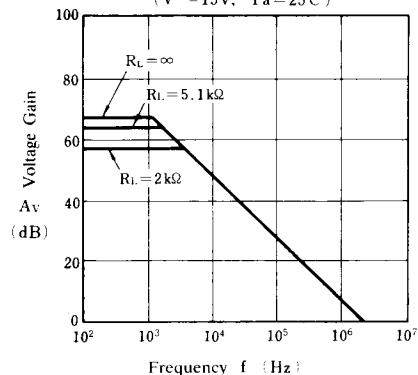
Maximum Mirror Current vs. Temperature

($V^+ = 15V$, $A_1 \geq 0.90$)



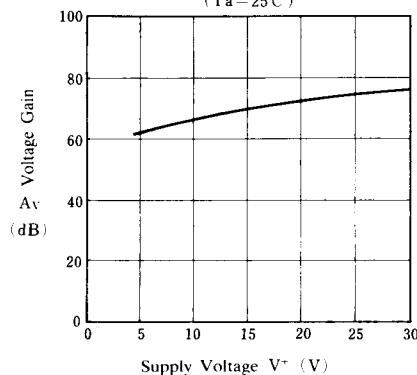
Voltage Gain vs. Frequency

($V^+ = 15V$, $T_a = 25^\circ C$)



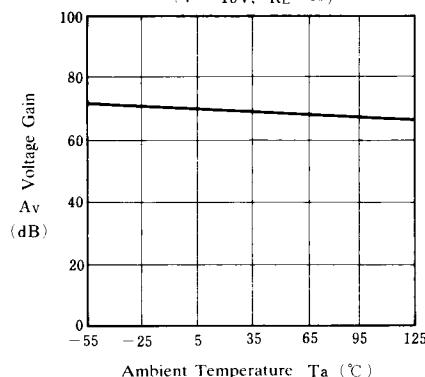
Voltage Gain vs. Supply Voltage

($T_a = 25^\circ C$)



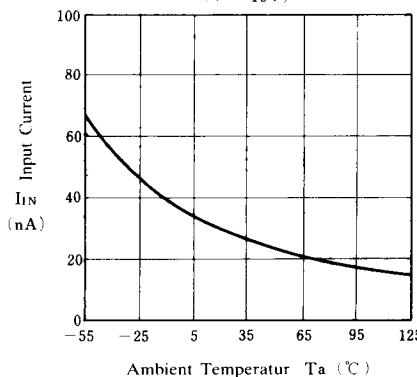
Voltage Gain vs. Temperature

($V^+ = 15V$, $R_L = \infty$)



Input Current vs. Temperature

($V^+ = 15V$)



■ Typical Characteristics

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